TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT process)

# 2SA1015(L)

## Audio Frequency Amplifier Applications Low Noise Amplifier Applications

• High voltage and high current:  $V_{CEO} = -50 \text{ V (min)}$ ,  $I_{C} = -150 \text{ mA (max)}$ 

• Excellent hFE linearity: hFE (2) = 80 (typ.) at  $V_{CE} = -6 \text{ V}$ ,  $I_{C} = -150 \text{ mA}$ : hFE ( $I_{C} = -0.1 \text{ mA}$ )/hFE ( $I_{C} = -2 \text{ mA}$ ) = 0.95 (typ.)

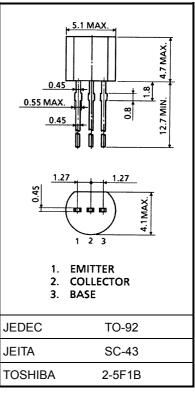
• Low noise: NF = 0.2dB (typ.) (f = 1 kHz)

• Complementary to 2SC1815 (L)

### Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	$V_{CBO}$	-50	V
Collector-emitter voltage	V <sub>CEO</sub>	-50	V
Emitter-base voltage	V <sub>EBO</sub>	-5	V
Collector current	IC	-150	mA
Base current	ΙΒ	-50	mA
Collector power dissipation	PC	400	mW
Junction temperature	Tj	125	°C
Storage temperature range	T <sub>stg</sub>	-55~125	°C

# Unit: mm

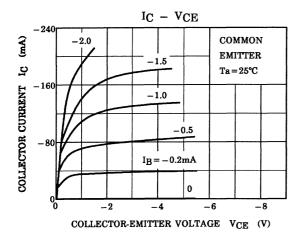


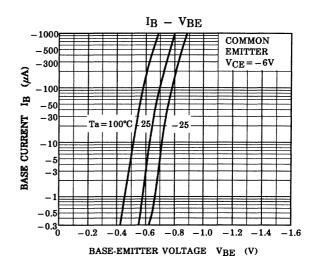
Weight: 0.21 g (typ.)

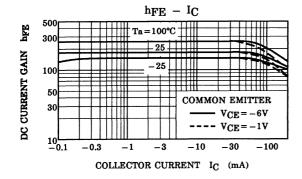
## **Electrical Characteristics (Ta = 25°C)**

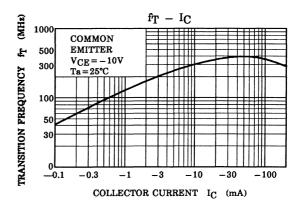
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I <sub>CBO</sub>	$V_{CB} = -50 \text{ V}, I_E = 0$	_	_	-0.1	μА
Emitter cut-off current	I <sub>EBO</sub>	$V_{EB} = -5 \text{ V}, I_C = 0$	_	_	-0.1	μА
DC current gain	h <sub>FE (1)</sub> (Note)	$V_{CE} = -6 \text{ V}, I_{C} = -2 \text{ mA}$	70	_	400	
	h <sub>FE (2)</sub>	$V_{CE} = -6 \text{ V}, I_{C} = -150 \text{ mA}$	25	80		
Collector-emitter saturation voltage	V <sub>CE (sat)</sub>	$I_C = -100 \text{ mA}, I_B = -10 \text{ mA}$		-0.1	-0.3	٧
Base-emitter saturation voltage	V <sub>BE (sat)</sub>	$I_C = -100 \text{ mA}, I_B = -10 \text{ mA}$	_	_	-1.1	V
Transition frequency	f <sub>T</sub>	$V_{CE} = -10 \text{ V}, I_{C} = -1 \text{ mA}$	80	_	_	MHz
Collector output capacitance	C <sub>ob</sub>	$V_{CB} = -10 \text{ V}, I_{E} = 0$ f = 1 MHz	_	4	7	pF
Base intrinsic resistance	r <sub>bb'</sub>	$V_{CB} = -10 \text{ V}, I_E = 1 \text{ mA}$ f = 30 MHz	_	30	_	Ω
Noise figure	NF (1)	$V_{CE} = -6 \text{ V}, I_{C} = -0.1 \text{ mA}$ f = 100 Hz, R <sub>G</sub> = 10 k $\Omega$	_	0.5	6	dB
	NF (2)	$V_{CE} = -6 \text{ V}, I_{C} = -0.1 \text{ mA}$ f = 1 kHz, R <sub>G</sub> = 10 k $\Omega$		0.2	3	ub

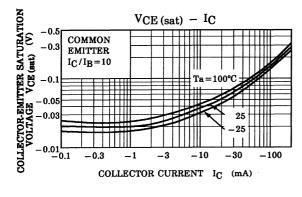
Note: h<sub>FE</sub> (1) classification O: 70~140, Y: 120~240, GR: 200~400

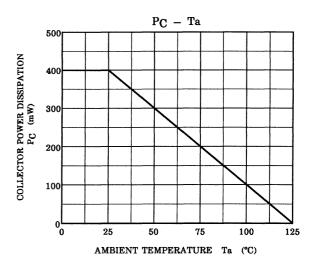


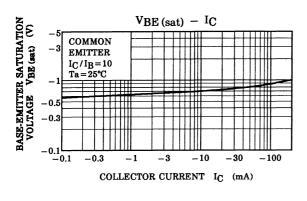












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